

Thermoelectric properties of the misfit cobaltate $\text{Ca}_3\text{Co}_4\text{O}_9$

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Abstract

The layered misfit cobaltate $\text{Ca}_3\text{Co}_4\text{O}_9$, also known as $\text{Ca}_2\text{CoO}_3[\text{CoO}_2]_{1.62}$, is a promising p-type thermoelectric oxide. Employing density functional theory, we study its electronic structure and determine, on the basis of Boltzmann theory within the constant-relaxation-time approximation, the thermoelectric transport coefficients. The dependence on strain and temperature is determined. In particular, we find that the xx -component of the thermopower is strongly enhanced, while the yy -component is strongly reduced, when applying 2% tensile strain. A similar anisotropy is also found in the power factor. The temperature dependence of the conductivity in the a - b plane is found to be rather weak above 200 K, which clearly indicates that the experimentally observed transport properties are dominated by inhomogeneities arising during sample growth, i.e., are not intrinsic.

Keywords: misfit cobaltate, thermoelectricity, density functional theory, relaxation time approximation

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I. INTRODUCTION

Since the discovery of a large thermoelectric power in the layered cobaltate NaCoO_2 two decades ago [1], this system and closely related ones, particularly $\text{Ca}_3\text{Co}_4\text{O}_9$ (CCO), have been studied intensively, both experimentally [2–26] as well as theoretically [27–32]; see also Refs. 33–35 for recent reviews. Layered cobalt oxides, such as CCO, are of interest because of the close proximity of the rock-salt Ca_2CoO_3 and hexagonal CoO_2 subsystems which results in a high Seebeck coefficient, low thermal conductivity, and, hence, high figure of merit at elevated temperature.

For example, Wakisaka et al. [13] have studied the electronic structure using x-ray photoemission spectroscopy, ultraviolet photoemission spectroscopy, and unrestricted Hartree-Fock calculations. They derive a charge-transfer energy of 1 eV between the Co sites in the Ca_2CoO_3 and CoO_2 subsystems as well as a d - d Coulomb interaction energy of 6.5 eV. Huang et al. [18] have investigated the structural, electrical, and thermal transport properties of CCO ceramics sintered in a high magnetic field, arguing that this technique is efficient for enhancing the thermopower. High-resolution photoemission spectroscopy has been used by Takeuchi et al. [6, 7] to investigate the electronic structure. These authors argue that the high thermopower is due to the metallic conduction in the hexagonal CoO_2 layers. According to Refs. 3 and 14, the rock-salt subsystem mainly shortens the phonon mean free path and thus lowers the thermal conductivity, while the hexagonal subsystem is responsible for the electrical conductivity. In addition, the magneto-transport properties are remarkable [2, 10, 17]; in particular, a high-temperature (above 600 K) spin state transition has been discovered very recently [36, 37].

First principles calculations have been performed by Asahi et al. [27] using a 3/2 ratio for the b_1 (rock-salt) and b_2 (CoO_2) lattice parameters, $(b_1/b_2)_{\text{exp}} = 1.62$, arguing that the optimized structure with distorted octahedra is in agreement with experiment. The authors report on p-type conductivity in the rock-salt subsystem, where the Fermi energy lies in the crystal-field gap of the $3d$ states of the CoO_2 subsystem. Tyson et al. [15] have combined temperature-dependent local structure measurements with first-principles calculations to develop a three-dimensional structure model of misfit $\text{Ca}_3\text{Co}_4\text{O}_9$. They find a low coordination of Co in the rock-salt layer, which is due to the formation of Co chains in the a - b plane linked to the CaO layers by Co-O bonds oriented along the c axis, enabling

high electrical and low thermal conductivity.

Combining experiment, ab-initio calculations, and semiclassical Boltzmann transport theory to investigate the anisotropy of the thermopower in $\text{Ca}_3\text{Co}_4\text{O}_9$ single crystals, Tang et al. [17] find a strongly anisotropic topology of the Fermi surface. Rébola et al. [29] have investigated the atomic and electronic structures employing density functional theory (DFT) and its extension (DFT+ U). Both methods lead to good agreement of the structural parameters with experiment.

In this work, we consider the 5/3 rational approximation, optimize the structure employing density functional theory (in the VASP implementation), and determine the thermoelectric transport coefficients on the basis of BoltzTrap. The transport properties are calculated for the pristine and for strained systems, as function of temperature. Substrate effects are discussed for a specific example (SrTiO_3).

In particular, we present the structure model in section II, and computational details in section III. The electronic structure and the thermoelectric properties are addressed in sections IV and V for pristine and strained CCO, respectively. Section VI is devoted to substrate effects, and some conclusions are given in the final section VII.

II. STRUCTURE MODEL

As mentioned above, the monoclinic structure of misfit $\text{Ca}_3\text{Co}_4\text{O}_9$ is built of rock-salt Ca_2CoO_3 sandwiched between hexagonal CoO_2 along the c direction. The subsystems share the a and c lattice parameters. The b lattice parameters differ so that a rational approximation with a minimal lattice mismatch has to be chosen. Asahi et al. [27] have used $b_1/b_2 = 3/2$ which corresponds to a mismatch of 7%, whereas the 5/3 ratio employed by Rébola et al. [29] reduces the mismatch to 3%. Contradicting experiment [6, 7], the 3/2 ratio results in $3d$ states of the Ca_2CoO_3 subsystem at the Fermi energy, while the 5/3 ratio leads only to minor contributions. Thus we consider $b_1/b_2 = 5/3$.

The a and c lattice parameters initially are set to the experimental values, whereas for the b lattice parameter a value of $5 \times 2.82 \text{ \AA} = 14.1 \text{ \AA}$ (taken from the CoO_2 subsystem) is used. The supercell then is fully optimized, with an on-site Coulomb interaction of 5 eV. The unrelaxed and relaxed structures are presented in Fig. 1. The optimized lattice parameters and corresponding bond lengths are summarized in Table I which also includes a comparison

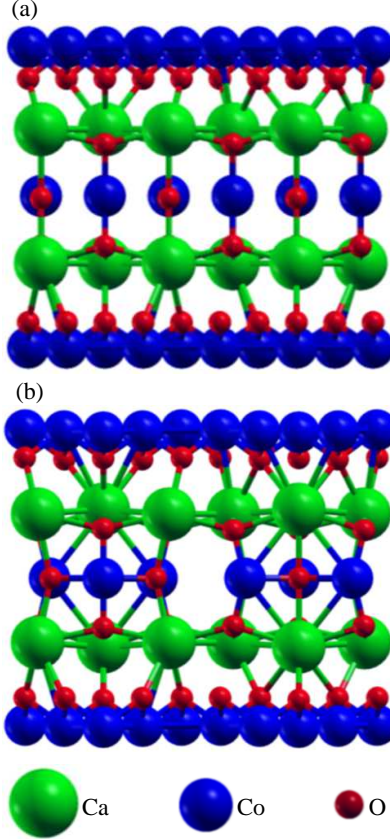


FIG. 1. Structure (a) before and (b) after the relaxation (5/3 ratio of CoO_2 and Ca_2CoO_3).

	a	b_1	b_2	c	β	Ca-O	Co ₁ -O ₁	Co ₁ -O ₂	Co ₂ -O (Å)
GGA	4.89 Å	4.70 Å	2.82 Å	10.73 Å	98.4°	2.46 Å	2.00 Å	1.82 Å	1.92 Å
GGA+U	4.88 Å	4.71 Å	2.82 Å	10.71 Å	98.4°	2.46 Å	2.01 Å	1.81 Å	1.92 Å
Exp. [29]	4.83 Å	4.56 Å	2.82 Å	10.84 Å	98.1°	2.40 Å	2.05 Å	2.30 Å	1.92 Å

TABLE I. Calculated and experimental structure parameters.

to experimental data. The optimized b lattice parameter is found to be determined by the CoO_2 subsystem (b_2), whereas the Ca_2CoO_3 subsystem (b_1) turns out to be intrinsically strained. Figure 1 indeed shows strong distortions in the rock-salt subsystem.

III. COMPUTATIONAL DETAILS

For the structural optimization we use the projector augmented wave method as implemented in the VASP code [38], relaxing both the atomic positions and lattice parameters.

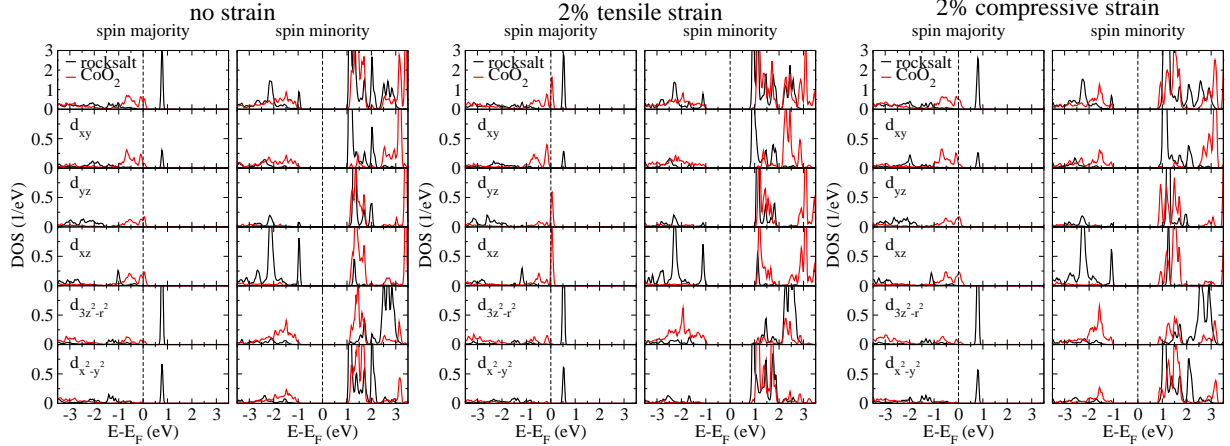


FIG. 2. Spin majority and minority densities of states without strain (left), under 2% tensile strain (middle), and under 2% (right) compressive volumetric strain. The DOS for 4% compressive strain is found to be almost indistinguishable from the latter.

A plane-wave cutoff energy of 530 eV and a residual force criterion of $0.02 \text{ eV}/\text{\AA}$ are used together with a Monkhorst-Pack $6 \times 2 \times 3$ k-mesh. The generalized gradient approximation in the Perdew-Burke-Ernzerhof flavor [39] is employed, and spin-polarization is taken into account.

In order to model the electronic correlations affecting the localized Co d states, on-site Coulomb repulsions of $U = 3 \text{ eV}$ and 5 eV (with $J = 1 \text{ eV}$) have been tested. For $U = 5 \text{ eV}$ the density of states is found to be in good agreement with the experiment [6, 7], whereas for $U = 3 \text{ eV}$ states of the Ca_2CoO_3 subsystem appear at the Fermi energy. It turns out that the self-consistent solution depends critically on the initial value of the Co magnetic moment. Values of 1, 1.5, and $2 \mu_B$ have been compared. In the former ($1 \mu_B$) case no substantial magnetic moments are formed in the CoO_2 subsystem, and the total energy is strongly reduced. Thus, only this case is further addressed. Both 2% and 4% compressive and 2% tensile volumetric strain are studied, for which the atomic positions are re-relaxed, respectively.

Precise electronic structures are obtained by the Wien2k [40] code using $U = 5 \text{ eV}$ and $J = 1 \text{ eV}$. The parameter $R_{mt}K_{max}$ is set to 8, with $G_{max} = 24$, and 320 k-points are considered in the irreducible wedge of the Brillouin zone. The transport properties are calculated using semi-classical Boltzmann theory, as implemented in the BoltzTraP code [41, 42], employing 2000 k-points in the irreducible wedge of the Brillouin zone.

We expect this procedure of calculating the transport coefficients to be applicable in the intermediate metallic regime, hence we show results only for T larger than 200 K. Furthermore, within the present approach, neither the structural change near 400 K [20] nor the spin state transition above 600 K [36, 37] is covered.

IV. ELECTRONIC STRUCTURE AND THERMOELECTRIC PROPERTIES

The density of states in the top row of Fig. 2 (left) shows that only the spin up Co $3d$ states of the CoO_2 subsystem contribute at the Fermi energy, in agreement with experiment [6, 7]. According to the orbitally projected densities of states these contributions are mainly due to the t_{2g} (d_{xy} , d_{xz} , and d_{yz}) orbitals. Fig. 2 (left) qualitatively agrees with the findings of Ref. 29; minor deviations can be attributed to the different computational schemes employed.

The thermoelectric properties are addressed in Fig. 3 where the left, middle, and right columns refer to the xx , yy , and zz components, respectively. Comparison of the calculated electrical conductivity at 300 K with the experiment in Ref. 4 ($\rho \simeq 10.7 \text{ m}\Omega \cdot \text{cm}$, where ρ denotes the resistivity) leads to a relaxation time of $3 \cdot 10^{-16} \text{ s}$, which is used in the following. We note that the conductivity is enhanced in the a - b plane (average of the xx and yy components). A maximal conductivity is achieved around 400 K. Positive values of the Seebeck coefficient reflect a hole character of the majority charge carriers. In the a - b plane the Seebeck coefficient increases with temperature and starts saturating around 400 K, which agrees well with the experiment [2], whereas the zz component does not saturate. At 300 K we find for the total Seebeck coefficient (average of the xx , yy , and zz components) a value close to $60 \mu\text{V}/\text{K}$, whereas in Refs. 27 and 29 values of $47 \mu\text{V}/\text{K}$ and $227 \mu\text{V}/\text{K}$, respectively, were predicted; and measurements result in $135 \mu\text{V}/\text{K}$ [2, 8, 19]. The power factor largely resembles the temperature dependence of the Seebeck coefficient.

V. STRAINED CCO

The densities of states obtained for strained CCO are shown in Fig. 2, for 2% tensile strain in the middle part, and 2% compressive volumetric strain in the right part of the figure, respectively. In both cases, similar to the unstrained system, only the spin up Co $3d$ states of the CoO_2 subsystem contribute at the Fermi energy, while the Ca_2CoO_3 subsystem

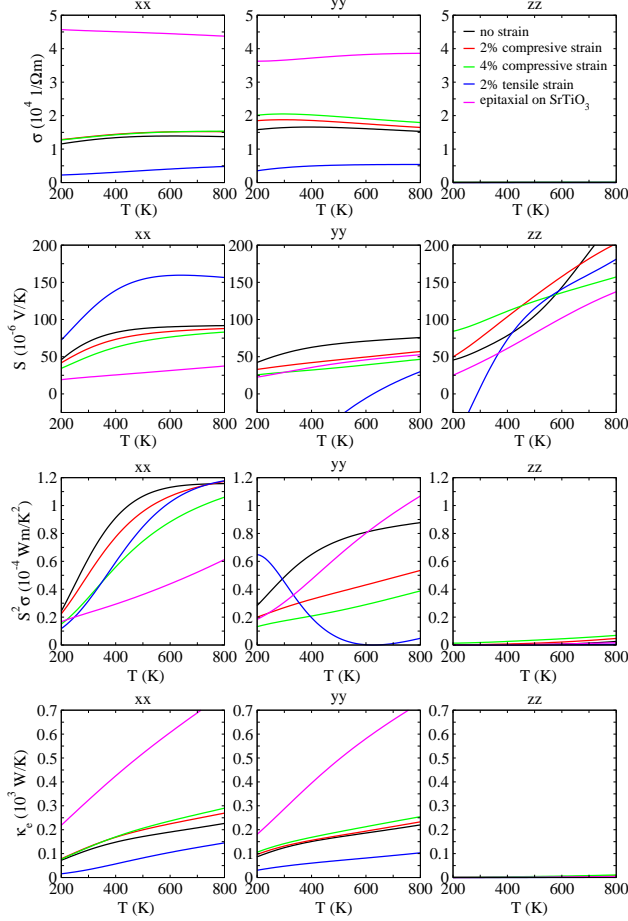


FIG. 3. Electrical conductivity (σ), Seebeck coefficient (S), power factor ($S^2\sigma$), and electronic part of the thermal conductivity (κ).

gives essentially no contributions at all. The same applies to the case of 4% compressive volumetric strain (not shown). The strained systems reproduce the gross features of the unstrained system, except for a shift of the spin down conduction band towards the Fermi energy for increasing compressive strain.

The electrical conductivity increases slightly with increasing compressive strain, see Fig. 3. The overall behaviors of the Seebeck coefficient and power factor as functions of the temperature do not change under compressive strain, but the values clearly decrease, particularly for the a - b plane. Interestingly, under tensile strain the electrical conductivity decreases significantly (because of an energetic shift and enhanced localization of the Co $3d$ states of the CoO₂ subsystem at the Fermi energy, see Fig. 2 (middle)), while the in-plane Seebeck coefficient increases at high temperature. The total Seebeck coefficient increases at high temperature more strongly than under compressive strain but less than for the unstrained

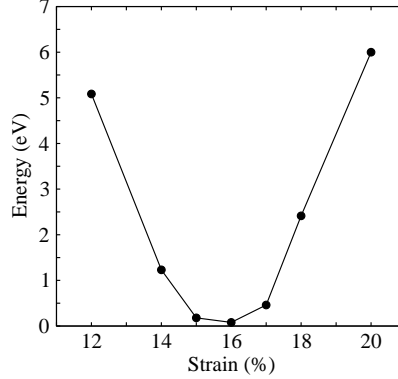


FIG. 4. Optimization of the c lattice parameter assuming 20% and 17% compression, respectively, for the a and b lattice parameters.

case. However, the decrease of the electrical conductivity leads to a decrease of the power factor under tensile strain. A strong anisotropy in the Seebeck coefficient in the a - b plane is apparent. The overall behavior of the thermal conductivity as function of strain is similar to the conductivity, except that κ increases approximately linearly in T .

VI. SUBSTRATE EFFECTS

It has been demonstrated for various substrates that first a rocksalt Ca_2CoO_3 buffer layer of up to 25 nm thickness is formed before the growth of $\text{Ca}_3\text{Co}_4\text{O}_9$ sets in [19]. The effect is stronger on (001)-oriented perovskite substrates than on hexagonal sapphire substrates, where the buffer layer extends only over few nm. Next to the buffer layer still many CoO_2 stacking faults are observed, which are assumed to enhance the phonon scattering and thus the Seebeck coefficient in films up to 50 nm thickness [19]. Due to the presence of the buffer layer, it seems unlikely that the substrate has a strong effect on $\text{Ca}_3\text{Co}_4\text{O}_9$. This point of view is also supported by the lattice parameters obtained from high-resolution electron microscopy [8]. However, in order to find out if in-plane strain from the substrate could have any positive effect on the thermoelectric performance, we study in the following a representative case, SrTiO_3 , explicitly.

To this aim, we strain the $\text{Ca}_3\text{Co}_4\text{O}_9$ supercell by forcing both the a and b lattice parameters (original values $a = 4.89 \text{ \AA}$ and $b = 14.1 \text{ \AA}$) to the lattice parameter of SrTiO_3 (3.905 \AA and $3 \times 3.905 \text{ \AA}$). This corresponds to rather strong compressions of 20% for a and 17%

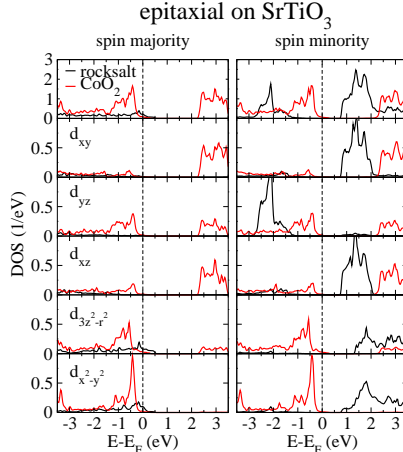


FIG. 5. Spin majority and minority densities of states when matching the in-plane lattice parameters to SrTiO₃.

for *b*. We then optimize the *c* lattice parameter relaxing the atomic positions, see Fig. 4, and obtain an expansion of 16% to 12.45 Å. Due to the strong distortions the densities of states in Fig. 5 show significant differences compared to Fig. 2 (right). The consequences for the thermoelectric properties are demonstrated in Fig. 3 by pink lines. As expected from the strong compression, the electrical and thermal conductivities increase, whereas the Seebeck coefficient and the power factor show no improvement over the unstrained material for most temperatures. These results indicate that Ca₃Co₄O₉ samples are not intrinsically strained and that such strain even would not be fruitful. Though it is computationally very demanding, a simulation of stacking faults could give further insights.

VII. CONCLUSION

In this work we have determined, on the basis of a DFT+*U* calculation which predicts a metallic ground state for the misfit cobaltate Ca₃Co₄O₉, the temperature dependence of the thermoelectric transport coefficients in the constant-relaxation-time approximation. We studied the pristine system (i.e., the 5/3 rational approximation) as well as its behavior under tensile and compressive strain. The results are expected to be applicable for not too low temperature, $T \gtrsim 200$ K. In order to explain the measured room-temperature resistivity [4], we have chosen the relaxation time to be given by $3 \cdot 10^{-16}$ s, slightly smaller than the value used in Ref. 32, $8 \cdot 10^{-16}$ s. Expressed in a different way, we find σ/τ to be given by

$\simeq 0.37 \cdot 10^{15} (\text{m}\Omega \cdot \text{cm} \cdot \text{s})^{-1}$, which is by about a factor of four larger than the corresponding value of Lemal et al. [32]. Note, however, that the reported resistivities vary considerably, ranging from $\simeq 2$ for single crystals [5] to $\simeq 170 \text{ m}\Omega \cdot \text{cm}$ for thin films fabricated on an LAO substrate using the PLD technique [22]. Another group, also using PLD but on (001)-silicon with a thin epitaxial yttria-stabilized zirconia (YSZ) buffer layer, reports $\simeq 2 - 13 \text{ m}\Omega \cdot \text{cm}$, depending on the microstructure [25]. Clearly these results indicate a strong dependence of transport properties on the growth conditions and the choice of substrate. (Note that we discuss in this paragraph only in-plane transport at room temperature.)

Finally we note that the conductivities found in CCO are considerably smaller than what is observed for other layered compounds, e.g., the delafossites PdCoO_2 and PtCoO_2 [43, 44], which might raise questions concerning the applicability of Boltzmann transport theory and/or the constant-relaxation-time approximation. In this context we also recall the simple fact that $\tau \lesssim 10^{-15}$ results in $\hbar/\tau \gtrsim 0.7 \text{ eV}$ which, naively speaking, would imply a considerable linewidth, comparable to the relevant energy scales in the density of states discussed above, in the electronic Green's functions. In our opinion, this clearly indicates that not all aspects of transport in CCO are sufficiently well understood. Luckily, the relaxation time cancels in the expression of the thermopower—but, even on the Boltzmann equation level, only in the simplest approximation.

ACKNOWLEDGMENTS

We acknowledge helpful discussions with Helmut Karl, Anke Weidenkaff, and Karol I. Wysokiński, as well as financial support by the Deutsche Forschungsgemeinschaft (through TRR 80). Research reported in this publication was supported by the King Abdullah University of Science and Technology (KAUST).

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